<b>PCN Number:</b> 20170220				0220001				PCN Date:	March 1, 2017		
Title	Title:         Qualification of TI Malaysia (TIM) as an additional Assembly & Test site for select devices						for select				
Cust	omer Contact:	PC	CN Manage	<u>er</u>	De	pt:	Quality S	ervic	es		
Proposed 1 <sup>st</sup> Ship Date: June 1			June 1	, 201					Date Provided at Sample equest		
Char	nge Type:										
$\square$	Assembly Site				De	esign			Wafer Bum	p Site	
	Assembly Proces	5			Da	Data Sheet			Wafer Bump Material		
Assembly Materials			Pa	Part number change			Wafer Bump Process				
Mechanical Specification		$\boxtimes$	Те	Test Site			Wafer Fab Site				
Packing/Shipping/Labeling			Те	st Process			Wafer Fab	Materials			
									Wafer Fab	Process	

# **PCN Details**

## **Description of Change:**

Texas Instruments Incorporated is announcing the qualification TI Malaysia (TIM) as Additional Assembly & test Site for select devices listed in the "Product Affected" Section. Current assembly sites and Material differences are as follows.

Assembly Site	Assembly Site Origin	Assembly Country Code	Assembly Site City
Amkor P1	AKR	PHL	Cupang, Muntinlupa City
TI Clark	QAB	PHL	Angeles City, Pampanga
TI Malaysia	MLA	MYS	Kuala Lumpur

### Material Differences:

#### Group 1 Devices (Assembly Only):

	Amkor P1	TI Malaysia
Mount compound	101374994	4208458
Mold compound	101325958	4222468
Lead finish	Sn	NiPdAu

#### Company Logo:

Amkor P1		TI Malaysia			
+ ! ! \NS/YMLLLLPG3 ! LM98555 ! CCMH ! ! ! O	+	+ ! ! \TI/YMLLLLSG4 ! LM98555 ! CCMH ! ! 0	+		
+	+	. • +	+		

#### Group 2 Devices (Assembly & Test):

didup = Berieco (no		
	TI Clark	TI Malaysia
Mount compound	4207123	4207768

Test coverage, insertions, conditions will remain consistent with current testing and verified with test MQ.

# **Reason for Change:**

Group 1 Device: Discontinuation of production line at AMKOR P1 for HTSSOP package device Group 2 Device: Continuity of supply for the QFN package device

Anticipated impact on Form, Fit, Function, Quality or Reliability (positive / negative):

Nor	ne						
An	ticipated impact on I	Mater	rial Declaration				
	No Impact to the Material Declaration		Material Declarations or Product Content reports are driven from production data and will be available following the production release. Upon production release the revised reports can be obtained at the site link below http://www.ti.com/quality/docs/materialcontentsearch.tsp				
Cha	anges to product ide	ntific	cation resulting from this PCN:				
	Assembly Site						
	MKOR P1		Assembly Site Origin (22L)	ASO: AKR			
Т	I-CLARK		Assembly Site Origin (22L)	ASO: QAB			
Т	I Malaysia		Assembly Site Origin (22L)	ASO: MLA			
		ı label	(not actual product label)	ASO. MLA			
Sa	TEXAS INSTRUMENTS MADE IN: Malaysia 20c: 20: MSL 2 /260C/1 YEAR SEAI MSL 1 /235C/UNLIM 03/2 OPT: ITEM: 39 BL: 5A (L)T0:17	G4 G4 29/04	(1P) \$N74L\$ (0) 2000 (31T)LOT: 3 (4W) TKY (1T (P) (2P) REV: (20L) CSO: SHE (22L) ASO: MLA				
Sa	TEXAS INSTRUMENTS MADE IN: Malaysia 20: 20: MSL '2 /260C/1 YEAR SEA MSL 1 /235C/UNLIM 03/: OPT: 39 LBL: 5A (L)T0:17 SEMBLY SITE CODES:	64 L DT 29/04 750 AKR	<ul> <li>(not actual product label)</li> <li>(1P) \$N74L\$</li> <li>(Q) 2000</li> <li>(31T) LOT: 3</li> <li>(4W) TKY (1T</li> <li>(P)</li> <li>(2D) CSO: SHE</li> <li>(2L) ASO: MLA</li> <li>= 4, QAB = I, MLA = K</li> </ul>	07NSR (D) 0336 1959047MLA ) 7523483512 (V) 0033317 (21L) CC0:USA			
Sa	TEXAS INSTRUMENTS MADE IN: Malaysia 20c: 20: MSL 2 /260C/1 YEAR SEAI MSL 1 /235C/UNLIM 03/2 OPT: ITEM: 39 BL: 5A (L)T0:17	64 L DT 29/04 750 AKR	<ul> <li>(not actual product label)</li> <li>(1P) \$N74L\$</li> <li>(Q) 2000</li> <li>(31T) LOT: 3</li> <li>(4W) TKY (1T</li> <li>(P)</li> <li>(2D) CSO: SHE</li> <li>(2L) ASO: MLA</li> <li>= 4, QAB = I, MLA = K</li> </ul>	07NSR (D) 0336 1959047MLA ) 7523483512 (V) 0033317 (21L) CC0:USA			
Sa Sa ASS Pro	TEXAS INSTRUMENTS MADE IN: Malaysia 20: 20: MSL '2 /260C/1 YEAR SEA MSL 1 /235C/UNLIM 03/: OPT: 39 LBL: 5A (L)T0:17 SEMBLY SITE CODES:	64 L DT 29/04 750 AKR 0 1 De	<ul> <li>(not actual product label)</li> <li>(1P) \$N74L\$</li> <li>(Q) 2000</li> <li>(31T) LOT: 3</li> <li>(4W) TKY (1T</li> <li>(P)</li> <li>(2D) CSO: SHE</li> <li>(2L) ASO: MLA</li> <li>= 4, QAB = I, MLA = K</li> </ul>	07NSR (D) 0336 1959047MLA ) 7523483512 (V) 0033317 (21L) CC0:USA			
Sa Sa ASS Pro	TEXAS INSTRUMENTS MADE IN: Malaysia 20: 20: MSL 2 /260C/1 YEAR SEAN MSL 1 /235C/UNLIM 03/2 OPT: ITEM: 39 LBL: 5A (L)T0:17 SEMBLY SITE CODES: Oduct Affected Group	<b>64</b> <b>1</b> DT <b>29/04</b> <b>750</b> AKR <b>1</b> Dc LM99	<pre>(not actual product label) (1P) \$N74L\$ (0) 2000 (31T)LOT: 3 (4W) TKY (1T (P) (2P) REV: (20L) CS0: SHE (22L) AS0: MLA = 4, QAB = I, MLA = K evices: 8555CCMHX/NOPB</pre>	07NSR (D) 0336 1959047MLA ) 7523483512 (V) 0033317 (21L) CC0:USA			

# **Group 1: Qualification Report** LM98555 AP1 Offload assembly to MLA (64 TSSOP)

Approved Date 15-Feb-2017

# **Product Attributes**

Attributes	Qual Device: LM98555
Assembly Site	TI MALAYSIA
Package Family	HTSSOP
Flammability Rating	UL 94 V-0
Wafer Fab Supplier	MAINEFAB
Wafer Process	CMOS7

- QBS: Qual By Similarity

- Qual Device LM98555 is qualified at LEVEL3-260C

# **Oualification Results**

Туре	Test Name / Condition	Duration	Qual Device: LM98555
AC	Autoclave 121C	96HRS	3/231/0
HTSL	High Temp Storage Bake 150C	1000HRS	3/231/0
THB	Biased Temperature and Humidity, 85C/85%RH	1000HRS	1/77/0
TC	Temperature Cycle, -65/150C	500CYC	3/231/0
VQR	Visual Quality Reliability	TMCL 500CYC	1/2/0
AC	Autoclave 121C	96HRS	3/231/0
MQ	Manufacturing Assembly	Per Specific site	3/pass
MSL	SAM	TMCL 500CYC	3/66/0
MSL	SAM	AFTER PRECOND	3/66/0
MSL	SAM	BEFORE PRECOND	3/66/0
VQR	Visual Quality Reliability	Post TMCL 500CYC	1/2/0
WBP	Bond Pull	wires	Pass
WBS	Bond Shear	Wires	Pass
PD	Package Dimension		1/30/0

#### Data Displayed as: Number of lots / Total sample size / Total failed

- Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

- The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours,

150C/300 Hours, and 155C/240 Hours

- The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours

- The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

#### Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

# Group 2: Qualification Report

#### BQ40Z551RSM Firmware Spin of BQ9000RSM in (RFAB Miho8/LBC7/TSMC FAB3, FAB10) 32-pin 4x4mm QFN in Clark and TIM

Approve Date 23-Feb-2016

Product Attributes						
Attributes	Qual Device: BQ40Z551RSM	QBS Product Reference: BQ9000RSM	QBS Product Reference: BQ9000RSM	QBS Process Reference: MSP430F5510IRGC	QBS Process Reference: TPIC2020RTQ	QBS Process Reference: TPS62110RSA
Assembly Site	TIM (A) AND CLARK (T)	CLARK	TIM (MAL)	MLA (TIM)	TI-CLARK	CAR
Package Family	QFN	QFN	QFN	VQFN	VQFN	QFN
Flammability Rating	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0	UL 94 V-0
Wafer Fab Supplier	MIHO8 OR RFAB, TSMC-FAB10 OR FAB3	RFAB, TSMC FAB 10	MIHO8, TSMC FAB 3	TSMC-10	RFAB	MIHO8
Wafer Process	0.18UM-28L- EFLASH, LBC7	0.18UM-28L- EFLASH, LBC7	0.18UM-28L- EFLASH, LBC7	TSMC EMB FLASH	LBC7	LBC7

- QBS: Qual By Similarity

- Qual Device BQ40Z551RSM is qualified at LEVEL2-260C

- Device BQ40Z551RSM contains multiple dies.

# **Qualification Results**

		Data	Displayed as: N		-	e size / Total failed		
Туре	Test Name / Condition	Duration	Qual Device: BQ40Z551RSM	QBS Product Reference: BQ9000RSM	QBS Product Reference: BQ9000RSM	QBS Process Reference: MSP430F5510IRGC	QBS Process Reference: TPIC2020RTQ	QBS Process Reference: TPS62110RSA
AC	Autoclave 121C	96 Hours	-	3/231/0	3/231/0	3/231/0	1/77/0	3/231/0
ED	Electrical Characterization	Per Datasheet Parameters	-	Pass	Pass	-	-	-
EDR	Non Volatile Memory Endurance 105C	20000 Cycles	-	-	-	3/42/0	-	-
EDR	Non Volatile Memory Endurance Room Temp	20000 Cycles	-	-	-	3/84/0	-	-
ELFR	Early Life Failure Rate, 140C	48 Hours	-	-	-	-	-	3/1881/0
ELFR	Early Life Failure Rate, 125C	24 Hours	-	-	-	3/2400/0	-	-
FW	Firmware Validation	EVM or Customer	Pass	-	-	-	-	-
HAST	Biased HAST, 130C/85%RH	96 Hours	-	3/231/0	3/78/0	3/231/0	1/77/0	3/231/0
HBM	ESD - HBM	1500 V	-	-	2/6/0	3/9/0	-	3/9/0
CDM	ESD - CDM	1000 V	-	2/6/0	2/6/0	-	-	-
HTOL	Life Test, 125C	1000 Hours	-	-	-	-	3/231/0	-
HTOL	Life Test, 140C	480 Hours	-	3/231/0	3/231/0	-	-	3/231/0
HTOL	Life Test, 150C Tj	300 Hours	-	-	-	3/231/0	-	-
HTSL	High Temp. Storage Bake, 150C	1000 Hours	-	-	-	-	1/77/0	-
HTSL	High Temp. Storage Bake, 170C	420 Hours	-	3/231/0	3/231/0	3/231/0	-	3/231/0
LU	Latch-up	(per JESD78)	-	3/36/0	3/38/0	3/18/0	3/38/0	3/15/0
SD	Solderability	8 Hours Steam Age	-	2/44/0	1/22/0	-	-	-
тс	Temperature Cycle, -65/150C	500 Cycles	-	3/231/0	3/231/0	3/231/0	3/231/0	3/231/0
TS	Thermal Shock, -65/150C	500 Cycles	-	-	-	-	-	3/231/0
WBP	Bond Strength	Wires	-	1/5/0	1/4/0	-	-	-
	and the production of the second		A (	LULA OT TUD		nnoratura Cycla Tharm		21

Data Displayed as: Number of lots / Total sample size / Total failed

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Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

For questions regarding this notice, e-mails can be sent to the regional contacts shown below or your local Field Sales Representative.

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